

RT1P250X SERIES

〈Transistor〉

Transistor With Resistor

For Switching Application

Silicon PNP Epitaxial Type

DESCRIPTION

RT1P250X is a one chip transistor with built-in bias resistor, NPN type is RT1N250X.

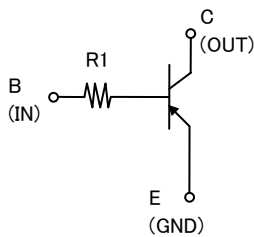
FEATURE

- Built-in bias resistor (R1=200k Ω).

APPLICATION

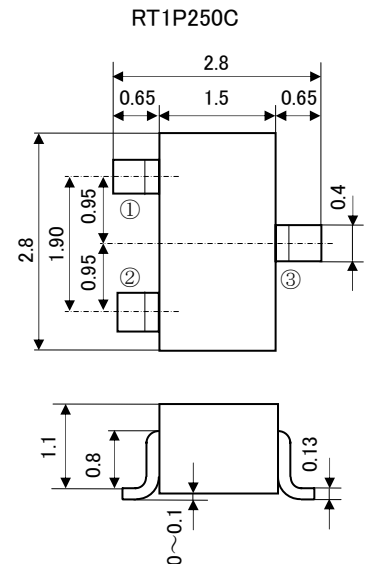
. Inverted circuit, switching circuit, interface circuit, driver circuit.

Equivalent circuit



OUTLINE DRAWING

UNIT : mm



JEITA : SC-59

JEDEC : Similar to TO-236

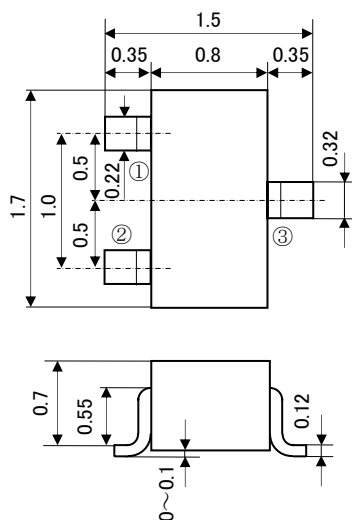
Terminal Connector

① : Base

② : Emitter

③ : Collector

RT1P250U



JEITA : SC-75A

JEDEC : —

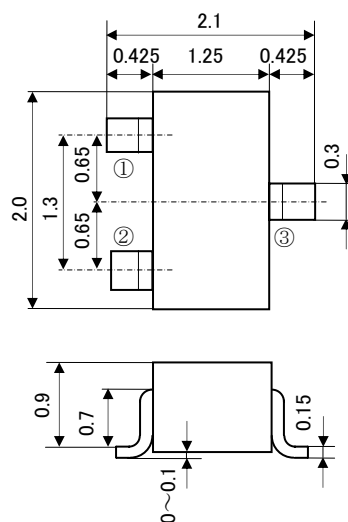
Terminal Connector

① : Base

② : Emitter

③ : Collector

RT1P250M



JEITA : SC-70

JEDEC : —

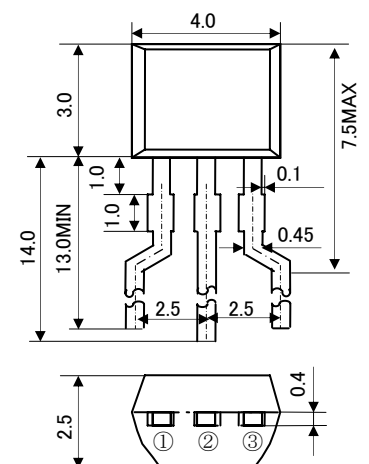
Terminal Connector

① : Base

② : Emitter

③ : Collector

RT1P250S



JEITA : —

JEDEC : —

Terminal Connector

① : Emitter

② : Collector

③ : Base

RT1P250X SERIES

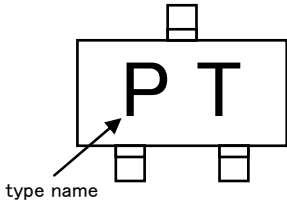
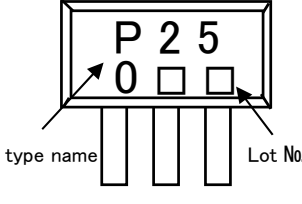
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MARKING

RT1P250C RT1P250M RT1P250U	RT1P250S
	

MAXIMUM RATING (Ta=25°C)

SYMBOL	PARAMETER	RATING				UNIT
		RT1P250U	RT1P250M	RT1P250C	RT1P250S	
V _{CBO}	Collector to Base voltage	-50				V
V _{EBO}	Emitter to Base voltage	-6				V
V _{CEO}	Collector to Emitter voltage	-50				V
I _C	Collector current	-100				mA
I _{CM}	Peak Collector current	-200				mA
P _C	Collector dissipation(Ta=25°C)	150	200		450	mW
Tj	Junction temperature	+150				°C
Tstg	Storage temperature	-55~+150				°C

ELECTRICAL CHARACTERISTICS (Ta=25°C)

SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
			MIN	TYP	MAX	
$V_{(BR)CEO}$	C to E break down voltage	$I_C = -100 \mu A, R_{BE} = \infty$	-50	—	—	V
I_{CBO}	Collector cut off current	$V_{CB} = -50V, I_E = 0$	—	—	-0.1	μA
I_{EBO}	Emitter cut off current	$V_{EB} = -5V, I_C = 0$	—	—	-0.1	μA
h_{FE}	DC forward current gain	$V_{CE} = -5V, I_C = -1mA$	100	—	—	—
$V_{CE(sat)}$	C to E saturation voltage	$I_C = -0.5mA, I_B = -0.05mA$	—	—	-0.3	V
R_1	Input resistor	—	140	200	260	k Ω
f_T	Gain band width product	$V_{CE} = -6V, I_E = 10mA$	—	150	—	MHz

RT1P250X SERIES

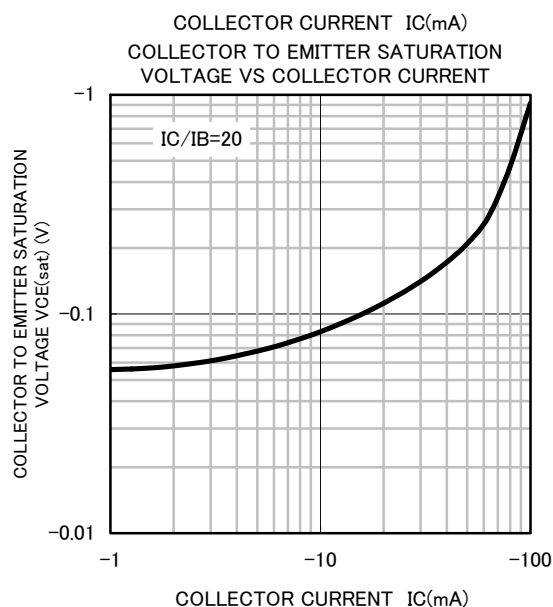
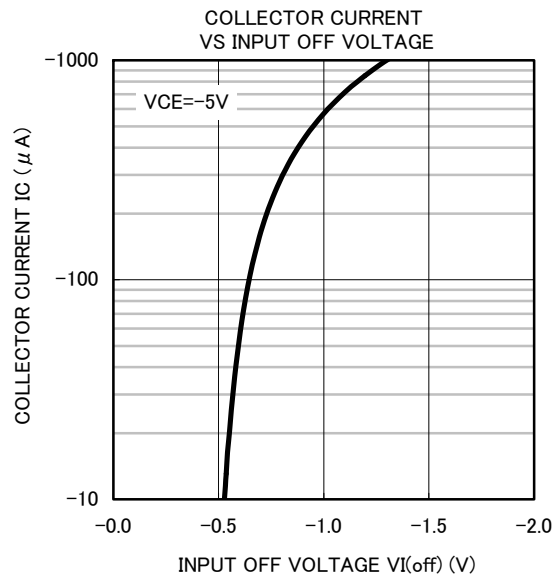
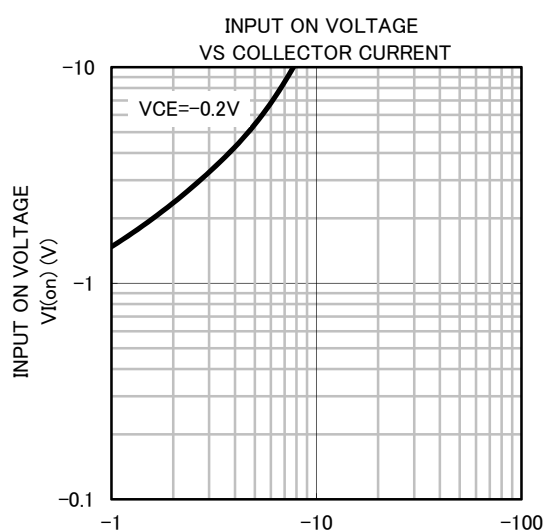
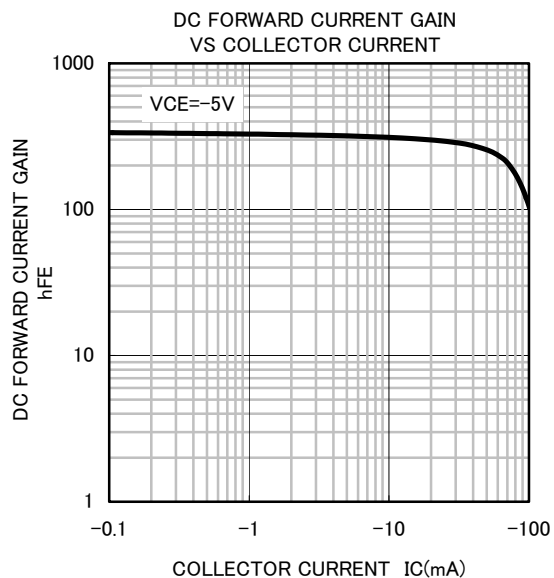
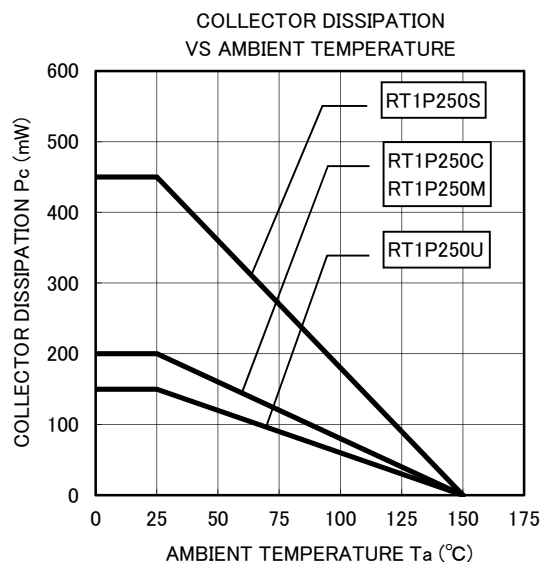
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TYPICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)





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